

High Efficiency Thyristor

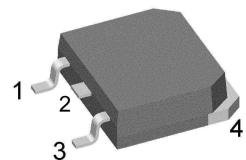
V_{RRM} = 1200 V
 I_{TAV} = 50 A
 V_T = 1.27 V

Single Thyristor

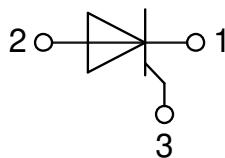
Part number

CLA50E1200TC

Marking on Product: *CLA50E1200TC*



Backside: anode



Features / Advantages:

- Thyristor for line frequency
- Planar passivated chip
- Long-term stability

Applications:

- Line rectifying 50/60 Hz
- Softstart AC motor control
- DC Motor control
- Power converter
- AC power control
- Lighting and temperature control

Package:

- TO-268AA (D3Pak)
- Industry standard outline
 - RoHS compliant
 - Epoxy meets UL 94V-0

Disclaimer Notice

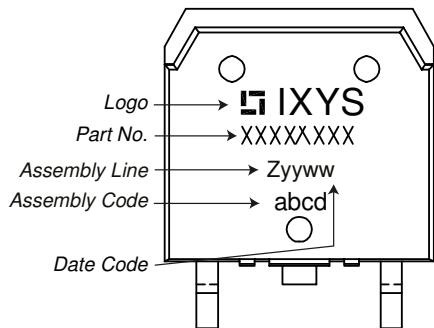
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Thyristor

Symbol	Definition	Conditions	Ratings			
			min.	typ.	max.	
$V_{RSM/DSM}$	max. non-repetitive reverse/forward blocking voltage	$T_{VJ} = 25^\circ\text{C}$			1300	V
$V_{RRM/DRM}$	max. repetitive reverse/forward blocking voltage	$T_{VJ} = 25^\circ\text{C}$			1200	V
$I_{R/D}$	reverse current, drain current	$V_{R/D} = 1200 \text{ V}$ $V_{R/D} = 1200 \text{ V}$	$T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$		50 4	μA mA
V_T	forward voltage drop	$I_T = 50 \text{ A}$	$T_{VJ} = 25^\circ\text{C}$		1.32	V
		$I_T = 100 \text{ A}$			1.60	V
		$I_T = 50 \text{ A}$ $I_T = 100 \text{ A}$	$T_{VJ} = 125^\circ\text{C}$		1.27 1.65	V
I_{TAV}	average forward current	$T_C = 125^\circ\text{C}$	$T_{VJ} = 150^\circ\text{C}$		50	A
$I_{T(RMS)}$	RMS forward current	180° sine			79	A
V_{T0}	threshold voltage	$\left. \begin{array}{l} \text{slope resistance} \\ \end{array} \right\} \text{for power loss calculation only}$	$T_{VJ} = 150^\circ\text{C}$		0.88	V
r_T	slope resistance				7.7	$\text{m}\Omega$
R_{thJC}	thermal resistance junction to case				0.25	K/W
R_{thCH}	thermal resistance case to heatsink			0.15		K/W
P_{tot}	total power dissipation		$T_C = 25^\circ\text{C}$		500	W
I_{TSM}	max. forward surge current	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$	$T_{VJ} = 45^\circ\text{C}$		650	A
		$t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$	$V_R = 0 \text{ V}$		700	A
		$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$	$T_{VJ} = 150^\circ\text{C}$		555	A
		$t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$	$V_R = 0 \text{ V}$		595	A
I^2t	value for fusing	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$	$T_{VJ} = 45^\circ\text{C}$		2.12	kA^2s
		$t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$	$V_R = 0 \text{ V}$		2.04	kA^2s
		$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$	$T_{VJ} = 150^\circ\text{C}$		1.54	kA^2s
		$t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$	$V_R = 0 \text{ V}$		1.48	kA^2s
C_J	junction capacitance	$V_R = 400 \text{ V}$ $f = 1 \text{ MHz}$	$T_{VJ} = 25^\circ\text{C}$	25		pF
P_{GM}	max. gate power dissipation	$t_p = 30 \mu\text{s}$	$T_C = 150^\circ\text{C}$		10	W
		$t_p = 300 \mu\text{s}$			5	W
P_{GAV}	average gate power dissipation				0.5	W
$(di/dt)_{cr}$	critical rate of rise of current	$T_{VJ} = 150^\circ\text{C}; f = 50 \text{ Hz}$ repetitive, $I_T = 150 \text{ A}$			150	$\text{A}/\mu\text{s}$
		$t_p = 200 \mu\text{s}; di_G/dt = 0.3 \text{ A}/\mu\text{s};$				
		$I_G = 0.3 \text{ A}; V = \frac{2}{3} V_{DRM}$ non-repet., $I_T = 50 \text{ A}$			500	$\text{A}/\mu\text{s}$
$(dv/dt)_{cr}$	critical rate of rise of voltage	$V = \frac{2}{3} V_{DRM}$	$T_{VJ} = 150^\circ\text{C}$		1000	$\text{V}/\mu\text{s}$
		$R_{GK} = \infty$; method 1 (linear voltage rise)				
V_{GT}	gate trigger voltage	$V_D = 6 \text{ V}$	$T_{VJ} = 25^\circ\text{C}$		1.5	V
			$T_{VJ} = -40^\circ\text{C}$		1.6	V
I_{GT}	gate trigger current	$V_D = 6 \text{ V}$	$T_{VJ} = 25^\circ\text{C}$		50	mA
			$T_{VJ} = -40^\circ\text{C}$		80	mA
V_{GD}	gate non-trigger voltage	$V_D = \frac{2}{3} V_{DRM}$	$T_{VJ} = 150^\circ\text{C}$		0.2	V
I_{GD}	gate non-trigger current				3	mA
I_L	latching current	$t_p = 10 \mu\text{s}$	$T_{VJ} = 25^\circ\text{C}$		125	mA
		$I_G = 0.3 \text{ A}; di_G/dt = 0.3 \text{ A}/\mu\text{s}$				
I_H	holding current	$V_D = 6 \text{ V}$ $R_{GK} = \infty$	$T_{VJ} = 25^\circ\text{C}$		100	mA
t_{gd}	gate controlled delay time	$V_D = \frac{1}{2} V_{DRM}$	$T_{VJ} = 25^\circ\text{C}$		2	μs
		$I_G = 0.3 \text{ A}; di_G/dt = 0.3 \text{ A}/\mu\text{s}$				
t_q	turn-off time	$V_R = 100 \text{ V}; I_T = 50 \text{ A}; V = \frac{2}{3} V_{DRM}$ $T_{VJ} = 125^\circ\text{C}$	$di/dt = 10 \text{ A}/\mu\text{s}$ $dv/dt = 20 \text{ V}/\mu\text{s}$ $t_p = 200 \mu\text{s}$	200		μs

Package TO-268AA (D3Pak)

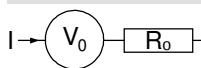
Symbol	Definition	Conditions	Ratings			
			min.	typ.	max.	
I_{RMS}	RMS current	per terminal			70	A
T_{VJ}	virtual junction temperature		-40		150	°C
T_{op}	operation temperature		-40		125	°C
T_{stg}	storage temperature		-40		150	°C
Weight				5		g
F_c	mounting force with clip		20		120	N

Product Marking

Part description

C = Thyristor (SCR)
 L = High Efficiency Thyristor
 A = (up to 1200V)
 50 = Current Rating [A]
 E = Single Thyristor
 1200 = Reverse Voltage [V]
 TC = TO-268AA (D3Pak) (2)

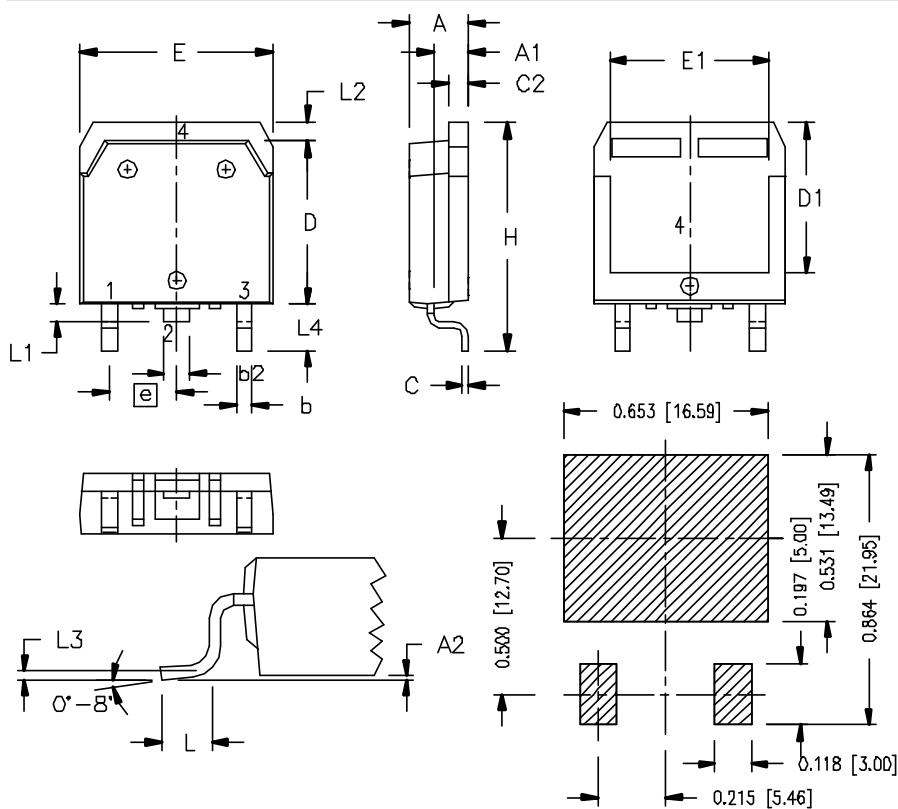
Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	CLA50E1200TC-TUB	CLA50E1200TC	Tube	30	502708
Alternative	CLA50E1200TC-TRL	CLA50E1200TC	Tape & Reel	400	502737

Similar Part	Package	Voltage class
CLA50E1200HB	TO-247AD (3)	1200

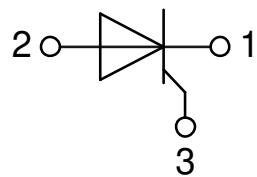
Equivalent Circuits for Simulation
** on die level*
 $T_{VJ} = 150 \text{ }^{\circ}\text{C}$

Thyristor

$V_{0\max}$ threshold voltage 0.88
 $R_{0\max}$ slope resistance * 5.2

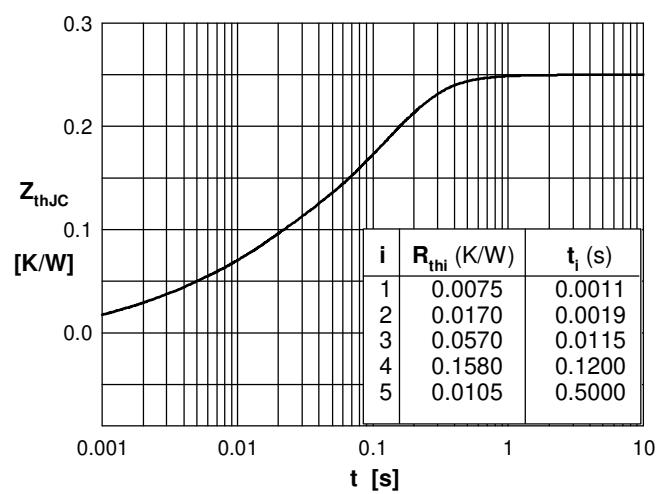
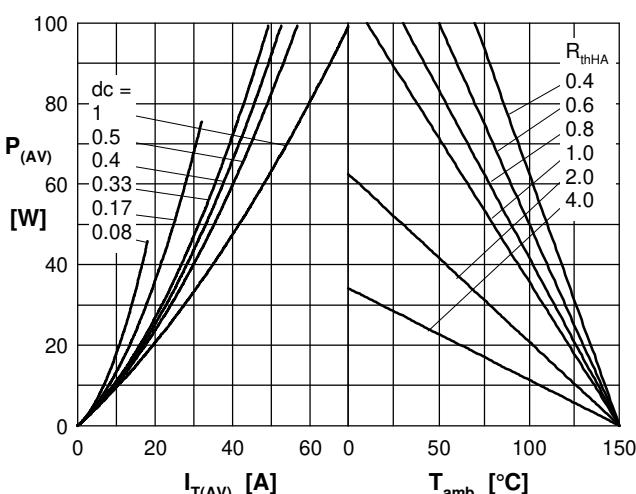
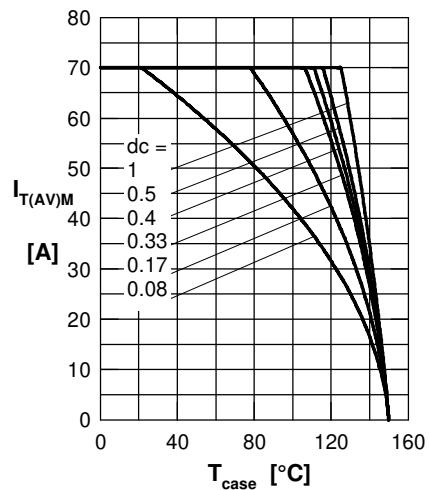
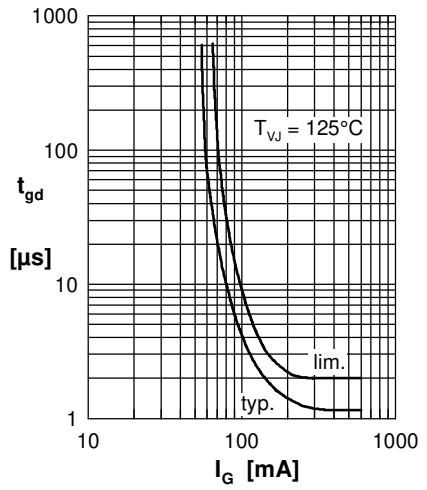
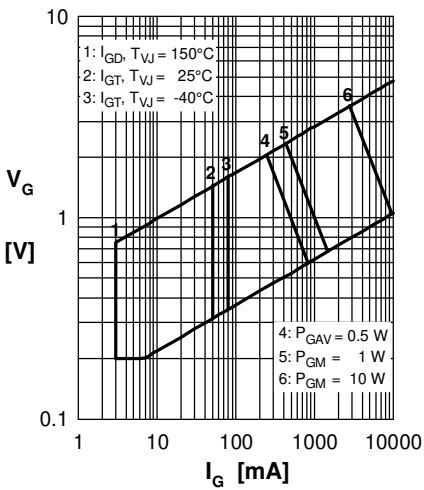
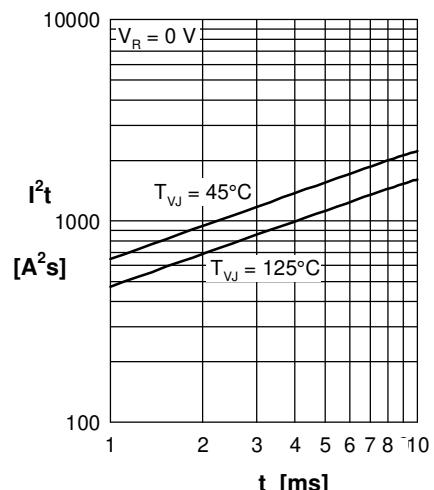
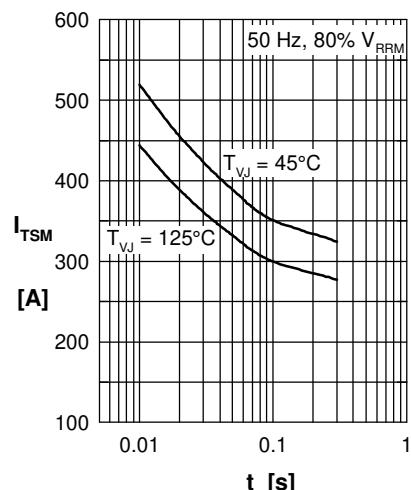
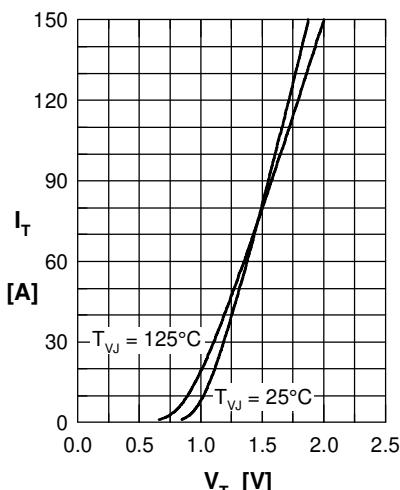
V
 mΩ

Outlines TO-268AA (D3Pak)


Dim.	Millimeter		Inches	
	min	max	min	max
A	4.90	5.10	0.193	0.201
A1	2.70	2.90	0.106	0.114
A2	0.02	0.25	0.001	0.100
b	1.15	1.45	0.045	0.057
b2	1.90	2.10	0.075	0.083
C	0.40	0.65	0.016	0.026
C2	1.45	1.60	0.057	0.063
D	13.80	14.00	0.543	0.551
D1	12.40	12.70	0.488	0.500
E	15.85	16.05	0.624	0.632
E1	13.30	13.60	0.524	0.535
e	5.45 BSC		0.215 BSC	
H	18.70	19.10	0.736	0.752
L	2.40	2.70	0.094	0.106
L1	1.20	1.40	0.047	0.055
L2	1.00	1.15	0.039	0.045
L3	0.25 BSC		0.100 BSC	
L4	3.80	4.10	0.150	0.161

RECOMMENDED MINIMUM FOOT PRINT FOR SMD


Thyristor



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